NSN 5962-01-102-3117

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-102-3117 **Body Length:** 1.290 inches **Body Width:** 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 575.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and bipolar and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 8 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts input **Time Rating Per Chacteristic:** 140.00 nanoseconds delay **Memory Device Type:** Prom **Test Data Document:** 81205-204-15515 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

NSN 5962-01-102-3117

Memory Microcircuit - Page 2 of 2



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